

Supporting Information

Boosting Photoelectrochemical Water Oxidation with Cobalt Phosphide Nanosheets on Porous BiVO₄

*Haili Tong, Yi Jiang, * Qian Zhang, Wenchao Jiang, Kaili Wang, Xiaoxi Luo, Ze Lin, and Lixin Xia**

College of Chemistry, Liaoning University, No. 66, Chongshan Middle Road, Huanggu District,
Shenyang 110036, People's Republic of China

*Corresponding authors.

E-mail addresses: jiangyi@lnu.edu.cn (Y Jiang); lixinxia@lnu.edu.cn (L Xia).

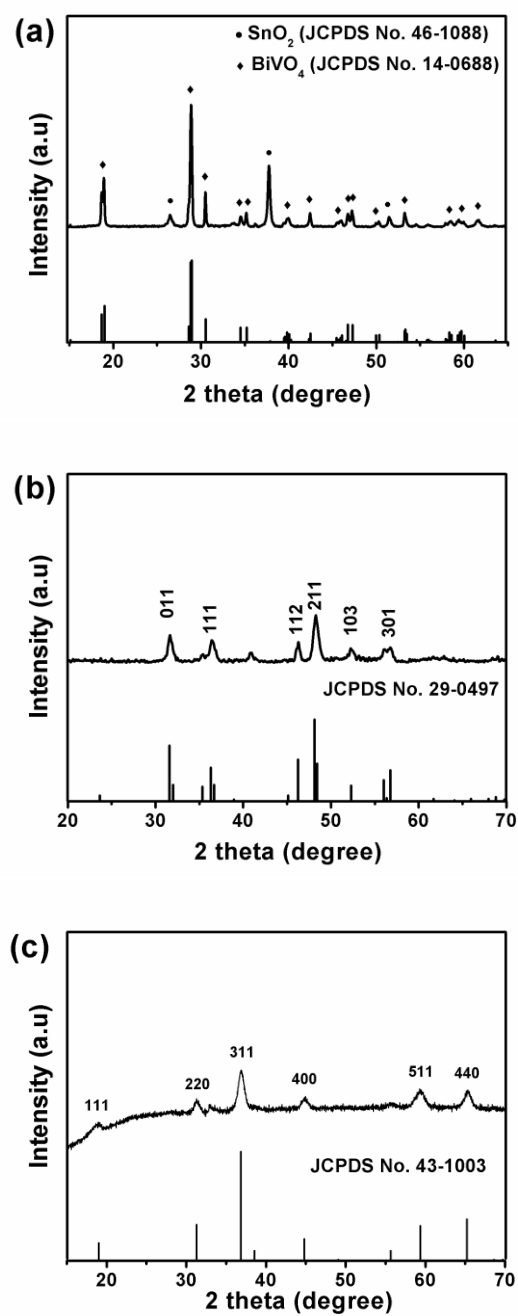


Figure S1. XRD patterns of (a) BiVO₄ electrode, (b) CoP powder and (c) Co₃O₄ powder.

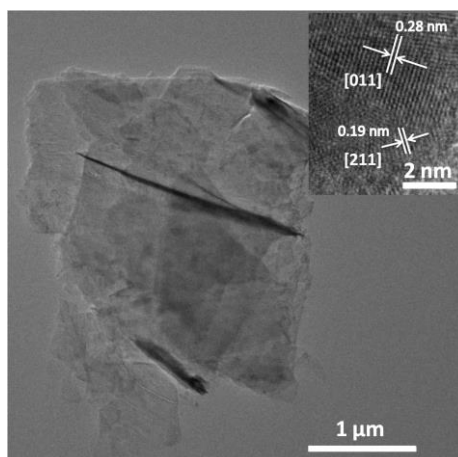


Figure S2. TEM and HRTEM images (inset right) of CoP nanosheets.

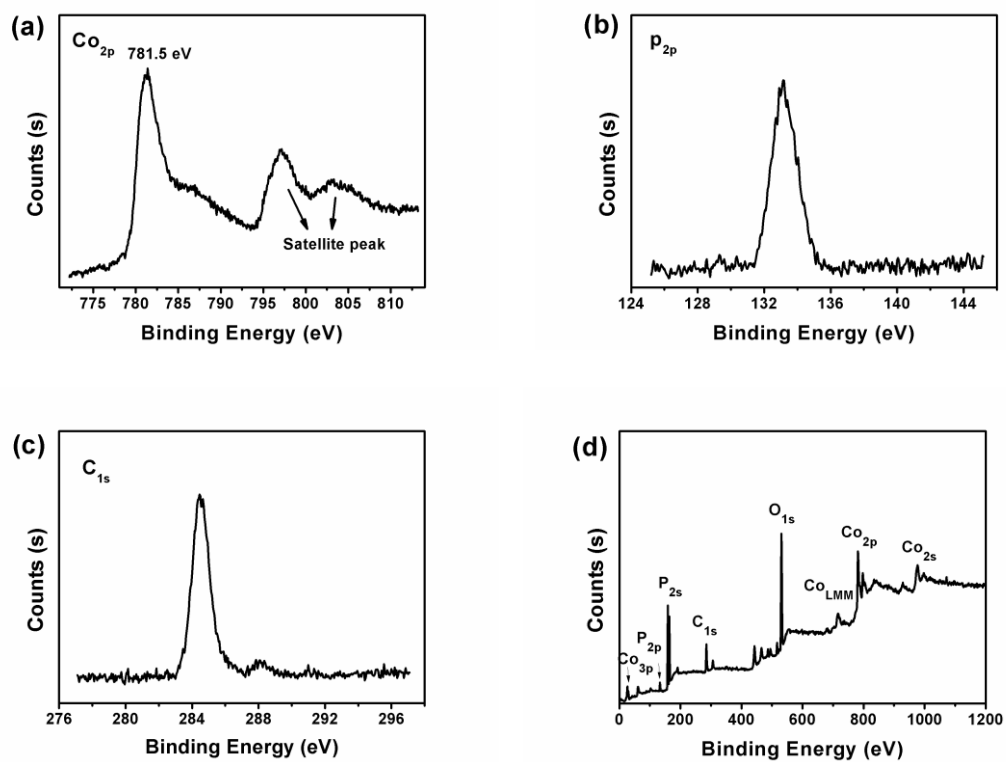


Figure S3. X-ray photoelectron spectroscopy (XPS) spectra of BiVO_4+CoP .

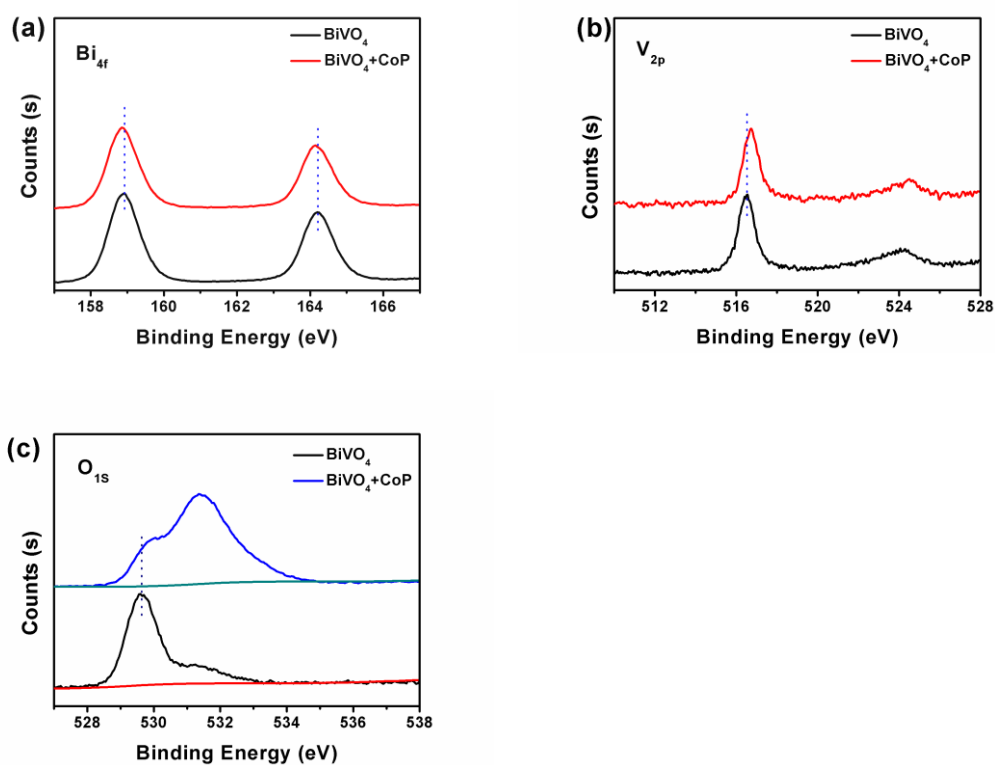


Figure S4. X-ray photoelectron spectroscopy (XPS) detailed spectra over the region of (a) Bi_{4f} , (b) V_{2p} and (c) O_{1s} of BiVO_4+CoP .

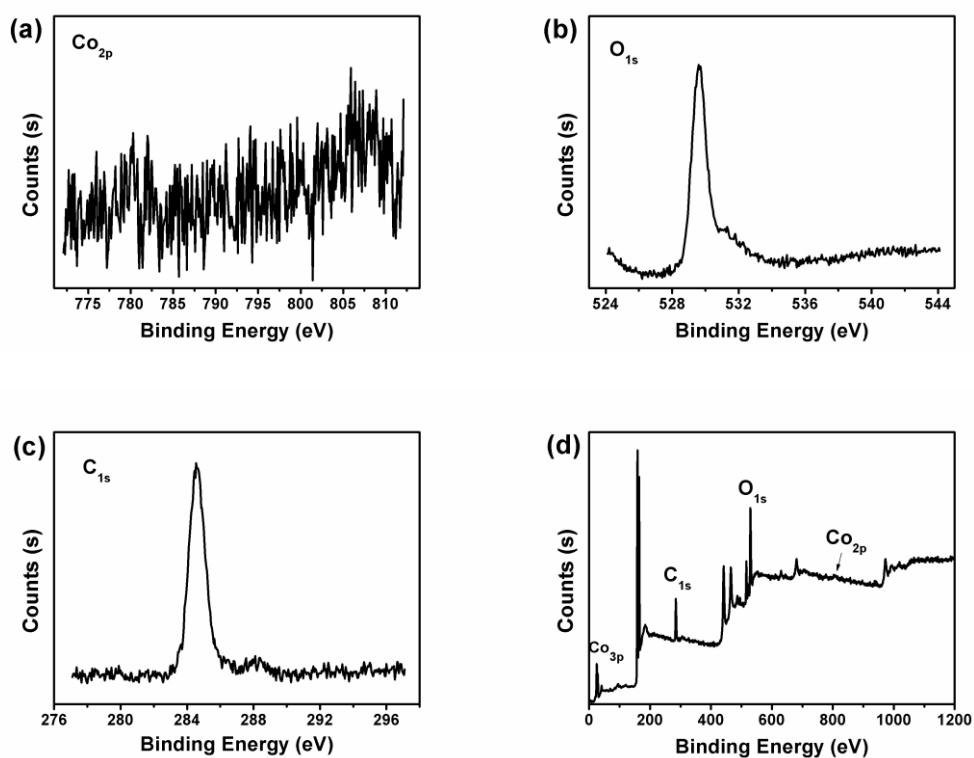


Figure S5. X-ray photoelectron spectroscopy (XPS) spectra of $\text{F BiVO}_4+\text{Co}_3\text{O}_4$.

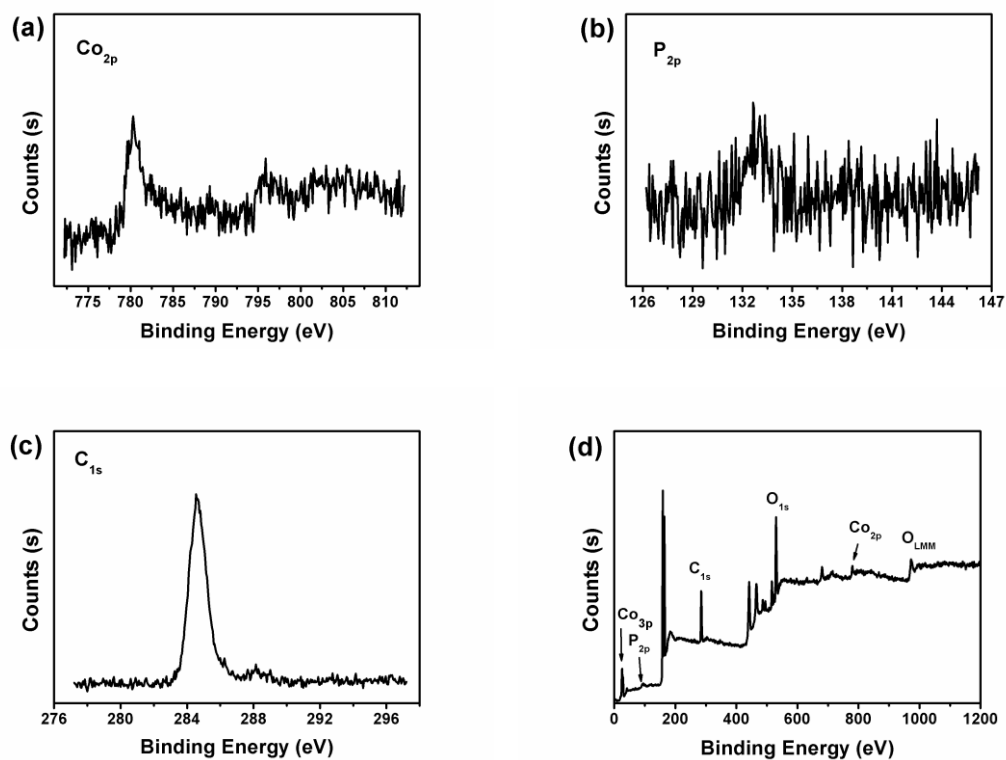
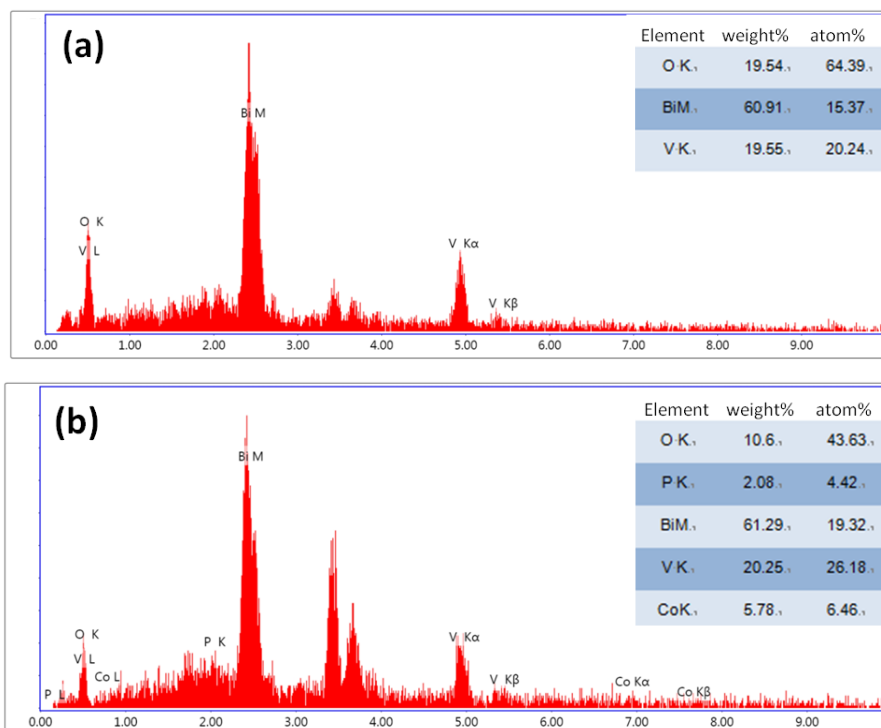


Figure S6. X-ray photoelectron spectroscopy (XPS) spectra of F BiVO₄+Co-Pi.



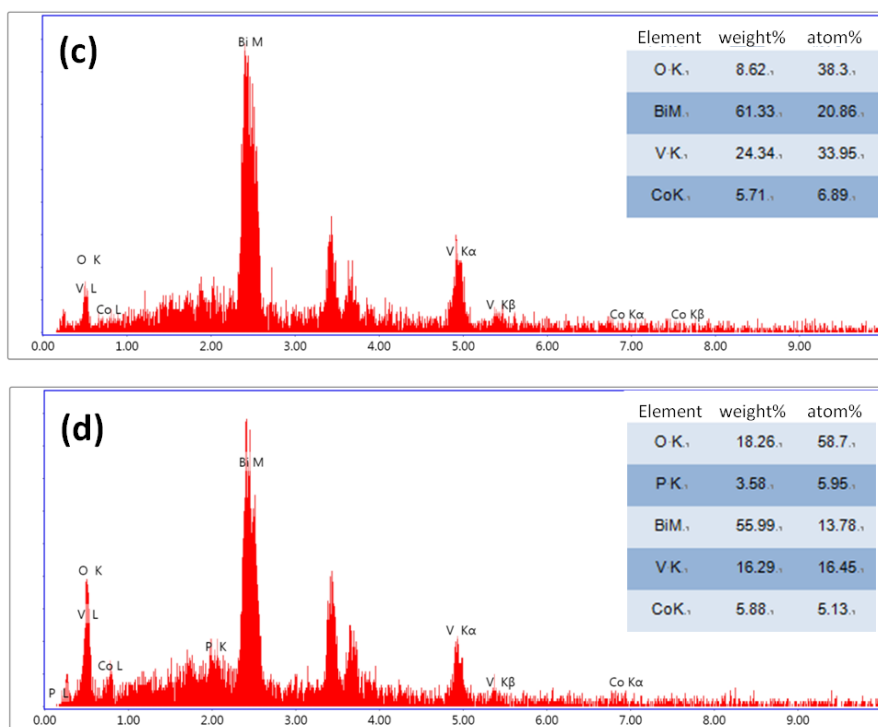


Figure S7. Energy dispersive spectrometry (EDS) of (a) BiVO_4 , (b) BiVO_4+CoP , (c) $\text{BiVO}_4+\text{Co}_3\text{O}_4$ and (d) $\text{BiVO}_4+\text{Co-Pi}$ electrodes.

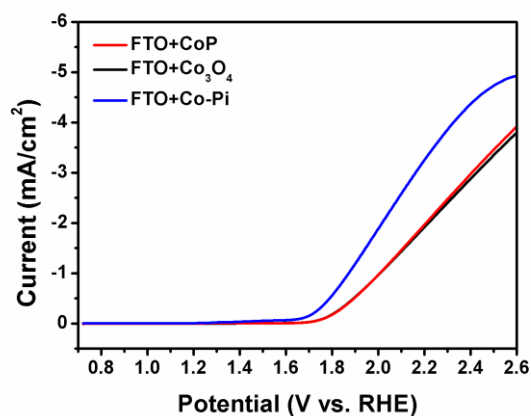


Figure S8. Photocurrent-potential characteristics of FTO+CoP (red); FTO+ Co_3O_4 (black) and FTO+Co-Pi (blue) electrodes measured (scan rate, 10 mV/s) under illumination ($100 \text{ mW}/\text{cm}^2$) in 0.2 M borate buffer (pH 9.0).

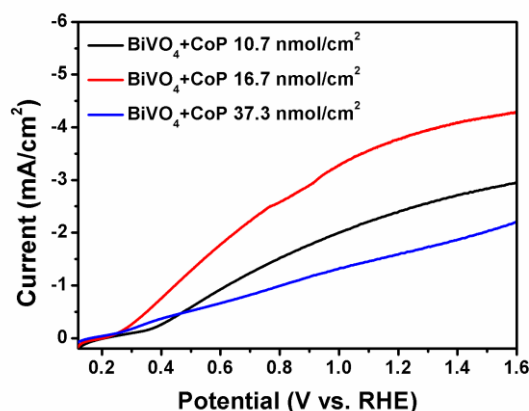


Figure S9. Photocurrent-potential characteristics of BiVO₄ photoanode modified by different concentration of CoP in 0.2 M borate buffer (pH 9.0) under illumination (100 mW/cm²).

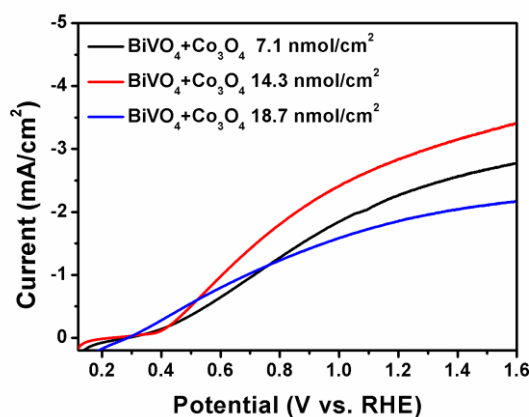


Figure S10. Photocurrent-potential characteristics of BiVO₄ photoanode modified by different concentration of Co₃O₄ in 0.2 M borate buffer (pH 9.0) under illumination (100 mW/cm²).

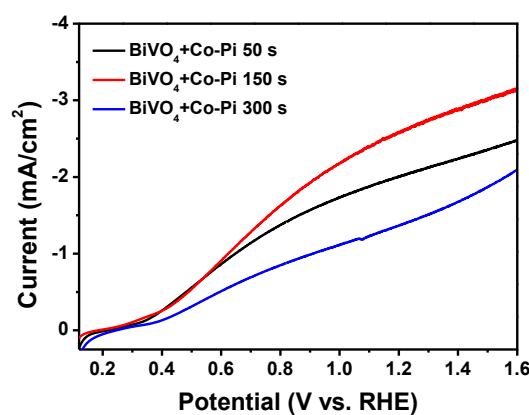


Figure S11. Photocurrent-potential characteristics of BiVO₄ photoanode modified by different electrodeposition time of Co-Pi in 0.2 M borate buffer (pH 9.0) under illumination (100 mW/cm²).

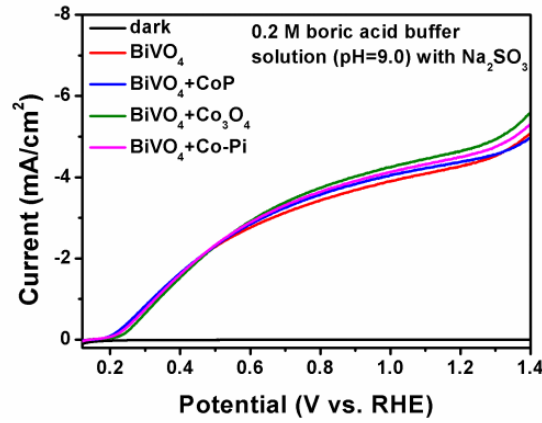


Figure S12. Photocurrent-potential characteristics of BiVO₄; BiVO₄+CoP; BiVO₄+Co₃O₄; BiVO₄+Co-Pi electrodes measured (scan rate, 10 mV/s) with and without illumination (100 mW/cm²) in 0.2 M borate buffer with 1 M Na₂SO₃.

J_{H_2O} (the photocurrent of water splitting) is a product of the rate of photon absorption expressed as a $J_{absorbed}$ (current density), $\eta_{charge\ separation}$ is the charge separation efficiency of the photogenerated holes that refer to the bulk recombination, and $\eta_{charge\ injection}$ is charge injection yield of the surface reaching holes into the electrolyte:

$$J_{H_2O} = J_{absorbed} * \eta_{charge\ separation} * \eta_{charge\ injection} \quad \text{Equation S1}$$

The photocurrent measured in the electrolyte with Na₂SO₃ ($J_{Na_2SO_3}$) is only a product of $J_{absorbed}$ and $\eta_{charge\ separation}$, assuming the charge injection yield becomes 100% ($\eta_{charge\ injection} = 1$) in the presence of a hole scavenger (Na₂SO₃) in the electrolyte:

$$J_{Na_2SO_3} = J_{absorbed} * \eta_{charge\ separation} \quad \text{Equation S2}$$

Based on equation S1 and S2, the charge injection yield can be achieved:

$$\eta_{charge\ injection} = J_{H_2O} / J_{Na_2SO_3} \quad \text{Equation S3}$$

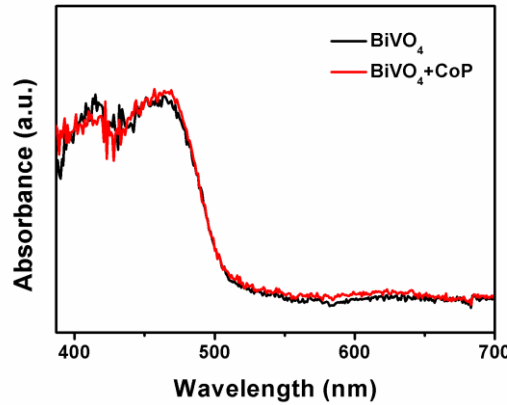


Figure S13. UV-Vis absorption spectra of bare BiVO₄ and BiVO₄+CoP photoanodes.

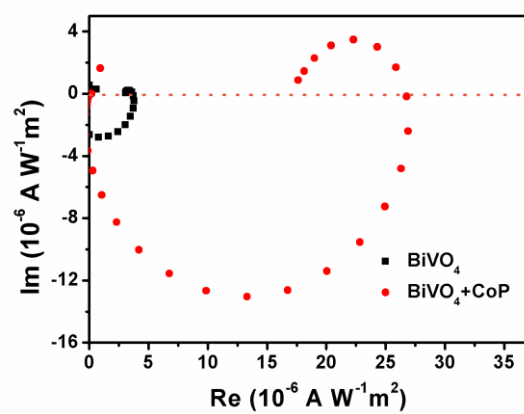


Figure S14. IMPS responses of BiVO₄ and BiVO₄+CoP photoanodes at 0.9 V vs. RHE.